



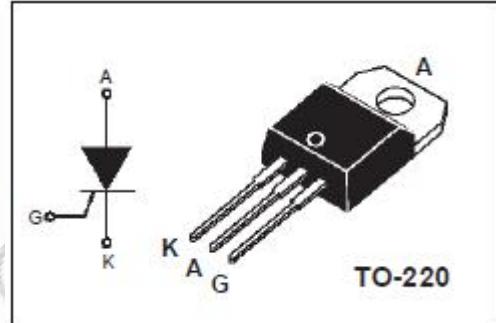
INCHANGE Semiconductor

## isc Thyristors

S6020L

**APPLICATIONS**

- With TO-220ins package
- It is suitable to fit all modes of control found in applications such as overvoltage crowbar protection,motor control circuits in power tools and kitchen aids,in-rush current limiting circuits, capacitive discharge ignition, voltage regulation circuits etc.
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	MIN	UNIT
$V_{DRM}$	Repetitive peak off-state voltage	600	V
$V_{RRM}$	Repetitive peak reverse voltage	600	V
$I_{T(RMS)}$	RMS on-state current	20	A
$I_T \text{ (AV)}$	Average on-state current	12.8	A
$I_{TSM}$	Surge non-repetitive on-state current	255 300	A
$T_j$	Operating junction temperature	-40~125	$^\circ\text{C}$
$T_{stg}$	Storage temperature	-40~125	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$  unless otherwise specified)**

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$I_{RRM}$	Repetitive peak reverse current	$V_R=V_{RRM}$ Rated; $V_D=V_{DRM}$ Rated;	0.01	0.5	mA
$I_{DRM}$	Repetitive peak off-state current	$T_c=25^\circ\text{C}$ $T_c=100^\circ\text{C}$ $T_c=125^\circ\text{C}$	1		
$V_{TM}$	On-state voltage			1.6	V
$I_{GT}$	Gate-trigger current	$V_D = 12\text{V}; RL = 60\ \Omega$ ;		30	mA
$V_{GT}$	Gate-trigger voltage	$V_D = 12\text{V}; RL = 60\ \Omega$ ;		1.5	V